

Switch Mode Power Rectifier

MUR1620CTRG, MURB1620CTRG, NRVUB1620CTRT4G

These state-of-the-art devices are designed for use in negative switching power supplies, inverters and as free wheeling diodes. Also, used in conjunction with common cathode dual Ultrafast Rectifiers, makes a single phase full-wave bridge.

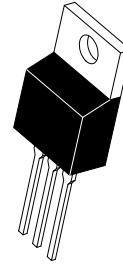
Features

- Common Anode Dual Rectifier (8.0 A per Leg or 16 A per Package)
- Ultrafast 35 Nanosecond Reverse Recovery Times
- Exhibits Soft Recovery Characteristics
- High Temperature Glass Passivated Junction
- Low Leakage Specified @ 150 °C Case Temperature
- Current Derating @ Both Case and Ambient Temperatures
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Complement to MUR1620CT and MURB1620CT Common Cathode Device
- ESD Ratings:
 - ◆ Machine Model = C (> 400 V)
 - ◆ Human Body Model = 3B (> 16,000 V)
- NRVU Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These are Pb-Free Devices*

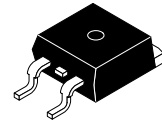
Mechanical Characteristics:

- Case: Epoxy, Molded
- Weight: MUR1620CTR: 1.9 Grams (Approximately)
MURB1620CTR: 1.7 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes:
260 °C Max. for 10 Seconds

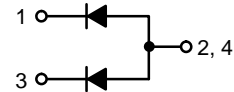
ULTRAFAST RECTIFIER 16 AMPERES, 200 VOLTS



TO-220AB
CASE 221A
STYLE 7



D²PAK
CASE 418AJ



MARKING DIAGRAMS



TO-220AB



D²PAK

U1620R = Device Code
KAK = Diode Polarity
A = Assembly Location
Y = Year
WW = Work Week
G = Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

NOTE: Some of the devices on this data sheet have been **DISCONTINUED**. Please refer to the table on page 2.

* For additional information on our Pb-Free strategy and soldering details, please download the [onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D](#).

MUR1620CTRG, MURB1620CTRG, NRVUB1620CTRT4G

MAXIMUM RATINGS (Per Leg)

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	200	V
Average Rectified Forward Current (Rated V_R , $T_C = 160\text{ }^\circ\text{C}$) Per Leg Per Total Device	$I_{F(AV)}$	8.0 16	A
Peak Repetitive Surge Current (Rated V_R , Square Wave, 20 kHz, $T_C = 140\text{ }^\circ\text{C}$) Per Diode	I_{FM}	16	A
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I_{FSM}	100	A
Operating Junction and Storage Temperature Range	T_J, T_{stg}	-65 to +175	$^\circ\text{C}$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS (Per Leg)

Characteristic	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	2.0	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-Ambient (D ² PAK)	$R_{\theta JA}$	45	$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS (Per Leg)

Characteristic	Symbol	Value	Unit
Maximum Instantaneous Forward Voltage (Note 1) ($i_F = 8.0\text{ Amps}$, $T_C = 25\text{ }^\circ\text{C}$) ($i_F = 8.0\text{ Amps}$, $T_C = 150\text{ }^\circ\text{C}$)	V_F	1.2 1.1	V
Maximum Instantaneous Reverse Current (Note 1) (Rated dc Voltage, $T_C = 25\text{ }^\circ\text{C}$) (Rated dc Voltage, $T_C = 150\text{ }^\circ\text{C}$)	i_R	5.0 500	μA
Maximum Reverse Recovery Time ($I_F = 1.0\text{ Amp}$, $di/dt = 50\text{ Amps}/\mu\text{s}$)	t_{rr}	85	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse Test: Pulse Width = 5.0 ms, Duty Cycle $\leq 10\%$.

ORDERING INFORMATION

Device	Package	Shipping†
MUR1620CTRG	TO-220 (Pb-Free)	50 Units / Rail
MURB1620CTRT4G	D ² PAK-3 (Pb-Free)	800 / Tape & Reel
NRVUB1620CTRT4G	D ² PAK-3 (Pb-Free)	800 / Tape & Reel

DISCONTINUED (Note 2)

MURB1620CTRG	D ² PAK-3 (Pb-Free)	50 Units / Rail
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† For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](#).

2. **DISCONTINUED:** These devices are not recommended for new design. Please contact your **onsemi** representative for information. The most current information on these devices may be available on www.onsemi.com.

MUR1620CTRG, MURB1620CTRG, NRVUB1620CTRT4G

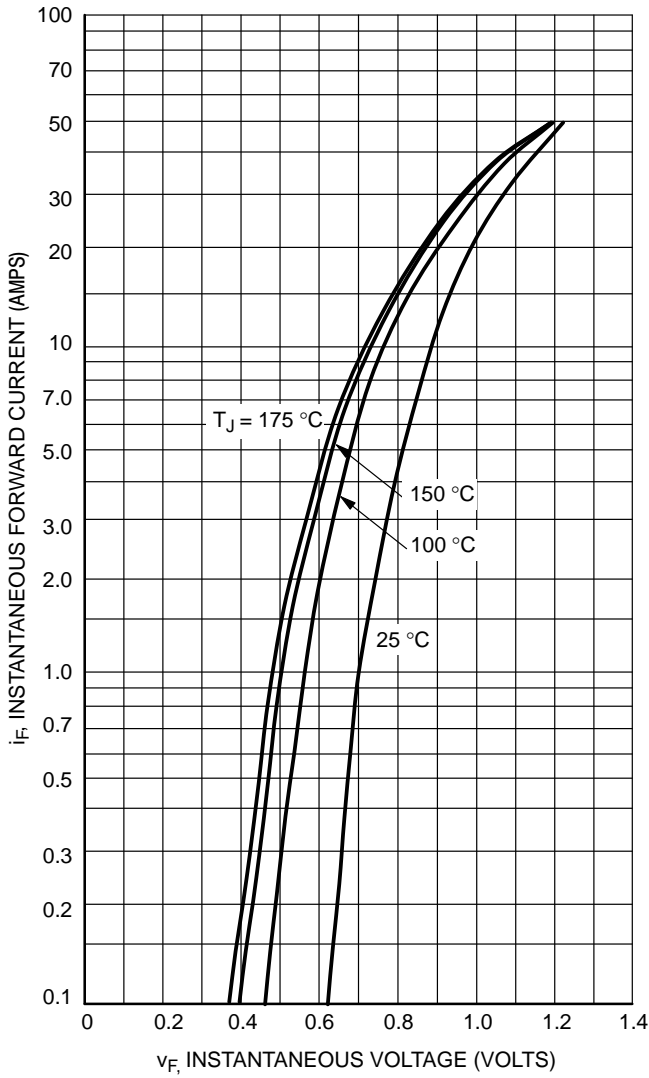


Figure 1. Typical Forward Voltage (Per Leg)

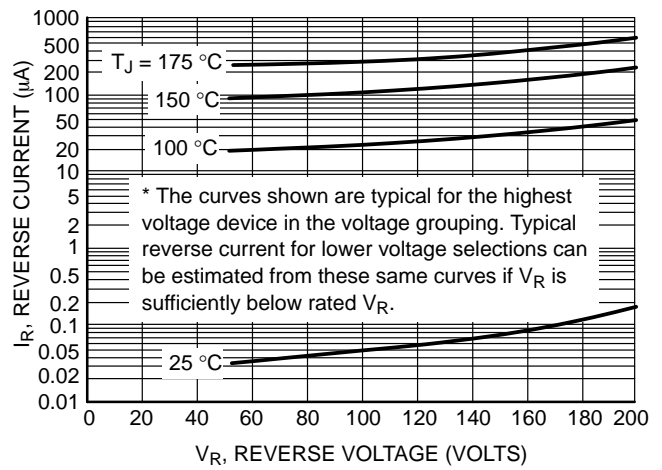


Figure 2. Typical Reverse Current* (Per Leg)

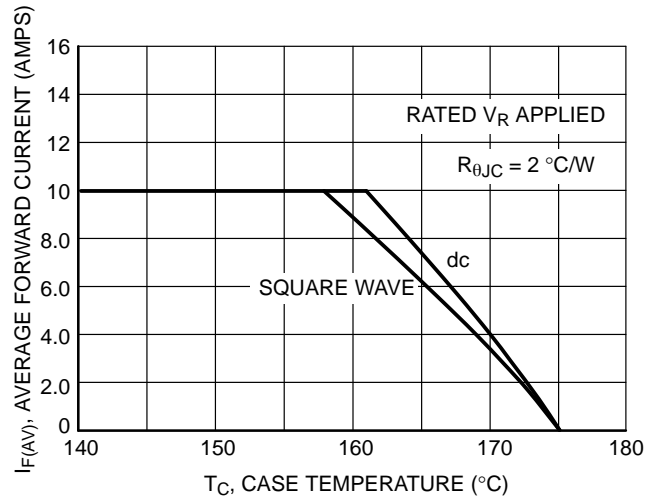


Figure 3. Current Derating, Case (Per Leg)

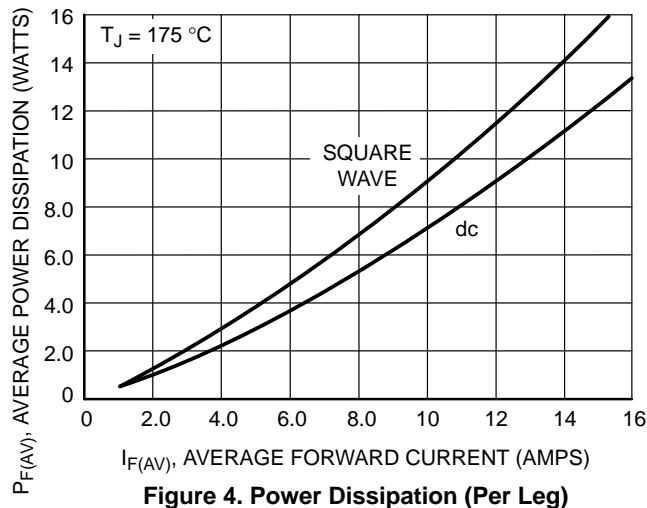


Figure 4. Power Dissipation (Per Leg)

MUR1620CTRG, MURB1620CTRG, NRVUB1620CTRT4G

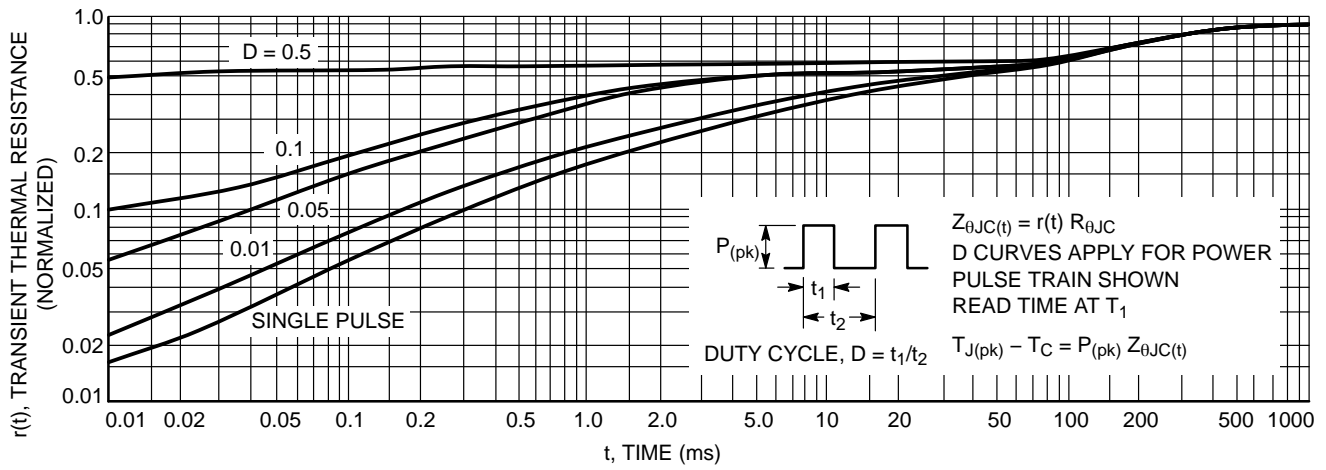


Figure 5. Thermal Response

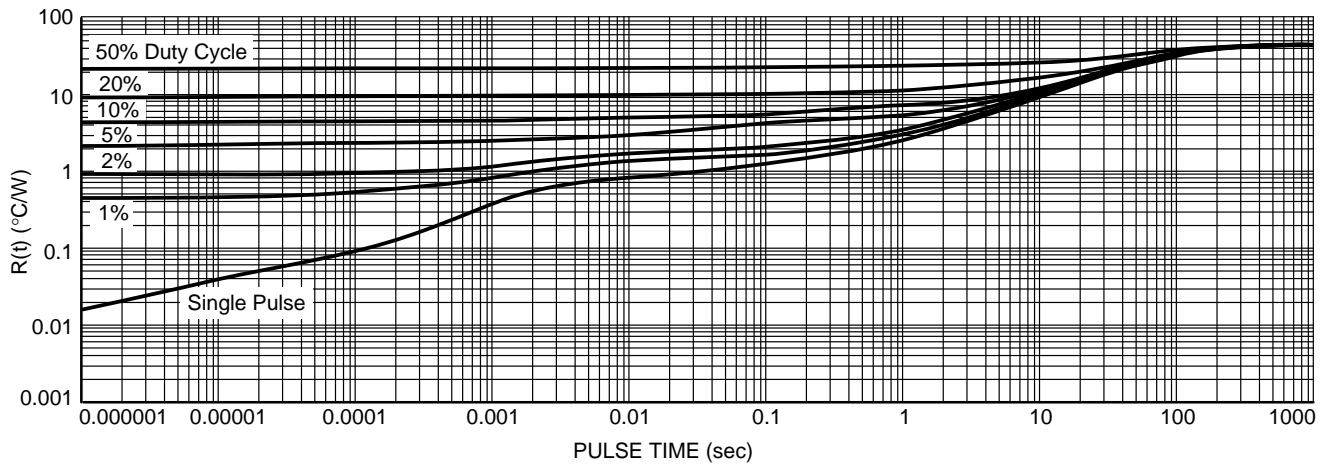


Figure 6. Thermal Response, Junction-to-Ambient

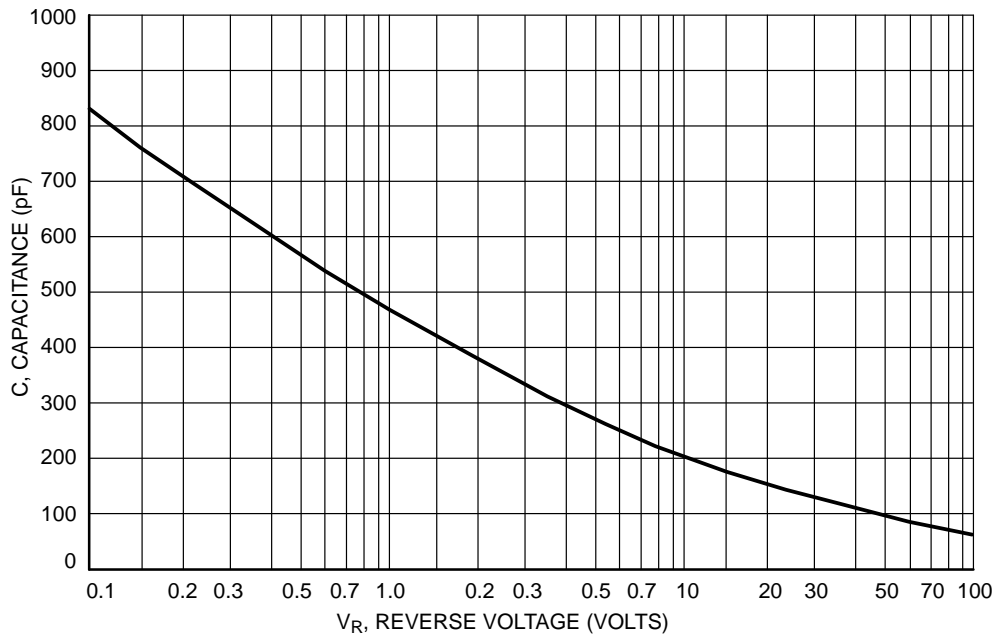


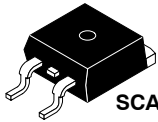
Figure 7. Typical Capacitance (Per Leg)

MUR1620CTRG, MURB1620CTRG, NRVUB1620CTRT4G

REVISION HISTORY

Revision	Description of Changes	Date
10	Rebranded the Data Sheet to onsemi format. MURB1620CTRG OPN marked as Discontinued.	10/14/2025

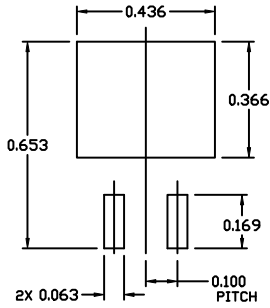
This document has undergone updates prior to the inclusion of this revision history table. The changes tracked here only reflect updates made on the noted approval dates.



SCALE 1:1

D²PAK-3 (TO-263, 3-LEAD)
CASE 418AJ
ISSUE F

DATE 11 MAR 2021



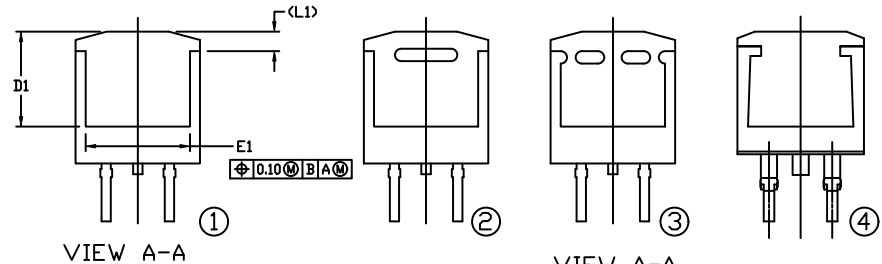
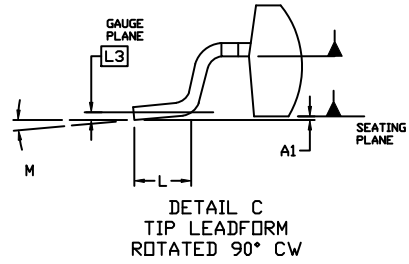
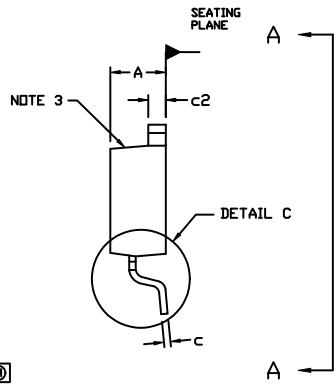
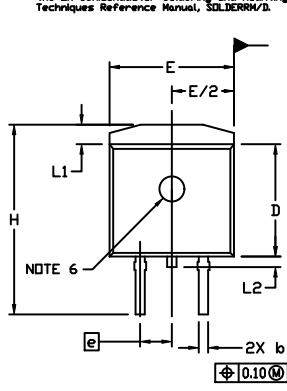
RECOMMENDED
MOUNTING FOOTPRINT

For additional information on our Pb-free strategy and soldering details, please download the IN Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERM/D.

NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
- CONTROLLING DIMENSION: INCHES
- CHAMFER OPTIONAL.
- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED 0.005 PER SIDE. THESE DIMENSIONS ARE MEASURED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY AT DATUM H.
- THERMAL PAD CONTOUR IS OPTIONAL WITHIN DIMENSIONS E, L1, D1, AND E1.
- OPTIONAL MOLD FEATURE.
- ①, ② ... OPTIONAL CONSTRUCTION FEATURE CALL OUTS.

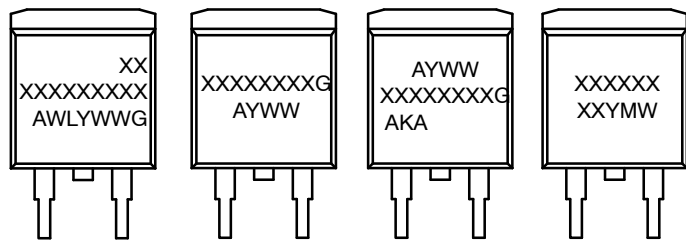
DIM	INCHES		MILLIMETERS	
	MIN.	MAX.	MIN.	MAX.
A	0.160	0.190	4.06	4.83
A1	0.000	0.010	0.00	0.25
b	0.020	0.039	0.51	0.99
c	0.012	0.029	0.30	0.74
c2	0.045	0.065	1.14	1.65
D	0.330	0.380	8.38	9.65
D1	0.260	---	6.60	---
E	0.380	0.420	9.65	10.67
E1	0.245	---	6.22	---
e	0.100 BSC	---	2.54 BSC	---
H	0.575	0.625	14.60	15.88
L	0.070	0.110	1.78	2.79
L1	---	0.066	---	1.68
L2	---	0.070	---	1.78
L3	0.010 BSC	---	0.25 BSC	---
M	0°	8°	0°	8°



VIEW A-A

VIEW A-A
OPTIONAL CONSTRUCTIONS

GENERIC MARKING DIAGRAMS*



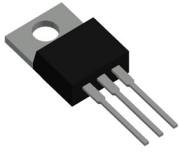
IC Standard Rectifier SSG

- XXXXXX = Specific Device Code
- A = Assembly Location
- WL = Wafer Lot
- Y = Year
- WW = Work Week
- W = Week Code (SSG)
- M = Month Code (SSG)
- G = Pb-Free Package
- AKA = Polarity Indicator

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

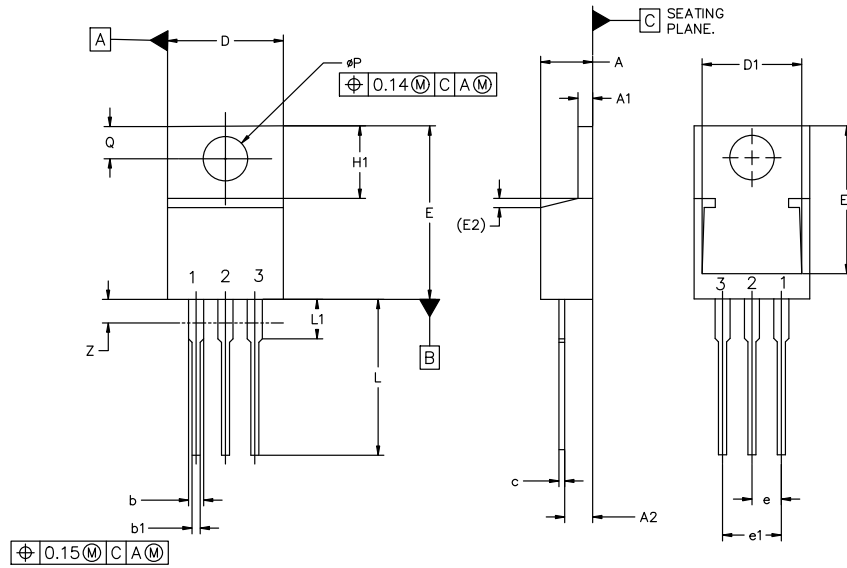
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DESCRIPTION:	D ² PAK-3 (TO-263, 3-LEAD)	PAGE 1 OF 1

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TO-220-3 10.10x15.12x4.45, 2.54P
CASE 221A
ISSUE AL

DATE 05 FEB 2025



MILLIMETERS			
DIM	MIN	NOM	MAX
A	4.07	4.45	4.83
A1	1.15	1.28	1.41
A2	2.04	2.42	2.79
b	1.15	1.34	1.52
b1	0.64	0.80	0.96
c	0.36	0.49	0.61
D	9.66	10.10	10.53
D1	8.43	8.63	8.83
E	14.48	15.12	15.75
E1	12.58	12.78	12.98
E2	1.27 REF		

MILLIMETERS			
DIM	MIN	NOM	MAX
e	2.42	2.54	2.66
e1	4.83	5.08	5.33
H1	5.97	6.22	6.47
L	12.70	13.49	14.27
L1	2.80	3.45	4.10
Q	2.54	2.79	3.04
φP	3.60	3.85	4.09
Z	---	---	3.48

- NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

- | | | | |
|--|--|---|--|
| <p>STYLE 1:
PIN 1. BASE
2. COLLECTOR
3. EMITTER
4. COLLECTOR</p> | <p>STYLE 2:
PIN 1. BASE
2. EMITTER
3. COLLECTOR
4. EMITTER</p> | <p>STYLE 3:
PIN 1. CATHODE
2. ANODE
3. GATE
4. ANODE</p> | <p>STYLE 4:
PIN 1. MAIN TERMINAL 1
2. MAIN TERMINAL 2
3. GATE
4. MAIN TERMINAL 2</p> |
| <p>STYLE 5:
PIN 1. GATE
2. DRAIN
3. SOURCE
4. DRAIN</p> | <p>STYLE 6:
PIN 1. ANODE
2. CATHODE
3. ANODE
4. CATHODE</p> | <p>STYLE 7:
PIN 1. CATHODE
2. ANODE
3. CATHODE
4. ANODE</p> | <p>STYLE 8:
PIN 1. CATHODE
2. ANODE
3. EXTERNAL TRIP/DELAY
4. ANODE</p> |
| <p>STYLE 9:
PIN 1. GATE
2. COLLECTOR
3. EMITTER
4. COLLECTOR</p> | <p>STYLE 10:
PIN 1. GATE
2. SOURCE
3. DRAIN
4. SOURCE</p> | <p>STYLE 11:
PIN 1. DRAIN
2. SOURCE
3. GATE
4. SOURCE</p> | <p>STYLE 12:
PIN 1. MAIN TERMINAL 1
2. MAIN TERMINAL 2
3. GATE
4. NOT CONNECTED</p> |

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DESCRIPTION:	TO-220-3 10.10x15.12x4.45, 2.54P	PAGE 1 OF 1

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